

NE5820M53

Data Sheet

P-channel MOS Field Effect Transistor for Impedance Converter of Microphone

R09DS0005EJ0200 Rev.2.00 May 20, 2011

DESCRIPTION

The NE5820M53 is a P-channel silicon MOSFET designed for use as impedance converter for microphone. The package is a 3-pin thin-type lead-less minimold, suitable for high-density surface mounting.

FEATURES

• Low noise : $N_V = -114 \text{ dBV TYP.}$ @ $V_{DD} = 2.0 \text{ V}$, $C_{in} = 3 \text{ pF}$, $R_L = 15 \text{ k}\Omega$

• Low input capacitance : C_{iss} = 1.5 pF TYP. @ V_{DD} = 2.0 V, R_L = 15 k Ω • Low consumption current : I_{DD} = 85 μ ATYP. @ V_{DD} = 2.0 V, R_L = 15 k Ω

• High-density surface mounting: 3-pin thin-type lead-less minimold $(1.2 \times 1.0 \times 0.33 \text{ mm})$

• Built-in the capacitor for RF noise immunity

· High ESD voltage

APPLICATIONS

Microphone, Sensor etc.

ORDERING INFORMATION

Part Number	Order Number	Package	Quantity	Marking	Supplying Form
NE5820M53-T1	NE5820M53-T1-A	3-pin thin-type	10 kpcs/reel	B8	Embossed tape 8 mm wide
		lead-less minimold			Pin 3 face the perforation
		(Pb-Free)			side of the tape

Remark To order evaluation samples, please contact your nearby sales office.

Part number for sample order: NE5820M53



Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The mark <R> shows major revised points.

The revised points can be easily searched by copying an "<R>" in the PDF file and specifying it in the "Find what:" field.



ABSOLUTE MAXIMUM RATINGS (T_A = +25°C, unless otherwise specified)

Paran	neter	Symbol	Ratings	Unit
Input Voltage	(IN-GND)	V_{in}	-0.8 to +0.8	V
Input Current	(IN-GND)	I _{in}	0.5	mA
Output Voltage	(OUT-GND)	V_{out}	–0.5 to +6	V
Output Current	(OUT-GND)	l _{out}	17	mA
Channel Temperature		T_ch	130	°C
Operating Ambie	ent Temperature	T _A	-40 to +95	°C
Storage Tempera	ature	T _{stg}	-65 to +150	°C

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RECOMMENDED OPERATING RANGE ($T_A = +25$ °C)

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
Supply Voltage Note	V_{DD}	1.0	2.0	10.0	>

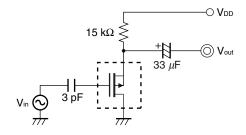
Note: $R_L = 15 \text{ k}\Omega$

ELECTRICAL CHARACTERISTICS $(T_A = +25^{\circ}C, R_L = 15 \text{ k}\Omega, \text{ unless otherwise specified})$

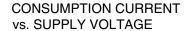
Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Consumption Current	I _{DD}	V _{DD} = 2 V, V _{in} = 0 V	60	85	105	μΑ
Input Capacitance	C _{iss}	V _{DD} = 2 V, f = 1 MHz	_	1.5	-	pF
Voltage Gain	G∨	V_{DD} = 2 V, V_{in} = 10 mVrms, C_{in} = 3 pF, f = 1 kHz, see TEST_CIRCUIT	-4.5	-3.0	_	dB
Reduced Voltage Characteristics	⊿G _{VV}	V_{DD} = 2 \rightarrow 1.5 V, V_{in} = 10 mVrms, C_{in} = 3 pF, f = 1 kHz, see TEST CIRCUIT	_	0.3	-	dB
Frequency Characteristics	∆G _{Vf}	V_{DD} = 2 V, V_{in} = 10 mVrms, C_{in} = 3 pF, f = 1 kHz \rightarrow 110 Hz, see TEST_CIRCUIT	_	0.05	_	dB
Output Noise Voltage	N _V	V_{DD} = 2 V, V_{in} = 0 Vrms, C_{in} = 3 pF, A-Curve, see TEST_CIRCUIT	_	-114	_	dBV
Total Harmonic Distortion	THD	V_{DD} = 2 V, V_{out} = 30 mVrms, C_{in} = 3 pF, f = 1 kHz, see TEST_CIRCUIT	_	0.1	_	%

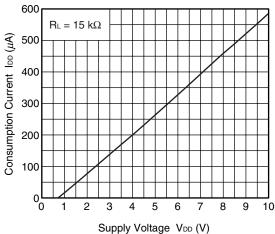
TEST CIRCUIT

Voltage Gain, Frequency Characteristics, Output Noise Voltage, Total Harmonic Distortion

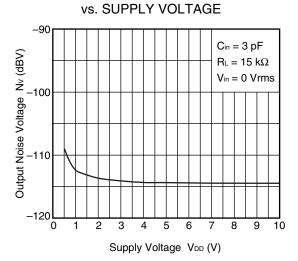


<R> TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)

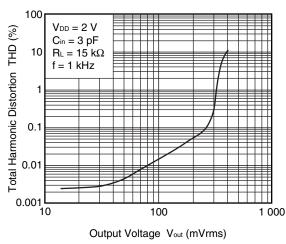




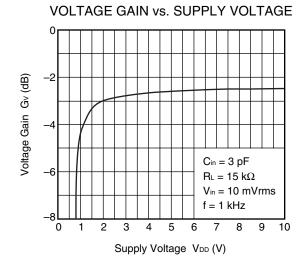
Supply Voltage V_{DD} (V) OUTPUT NOISE VOLTAGE



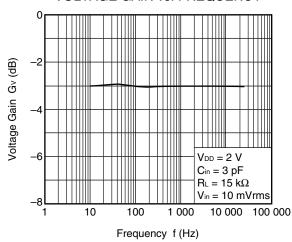
TOTAL HARMONIC DISTORTION vs. OUTPUT VOLTAGE



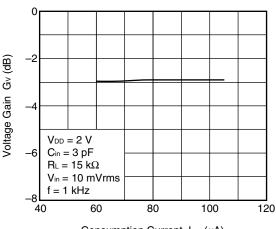
Remark The graphs indicate nominal characteristics.



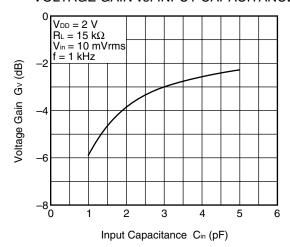
VOLTAGE GAIN vs. FREQUENCY



VOLTAGE GAIN vs. CONSUMPTION CURRENT

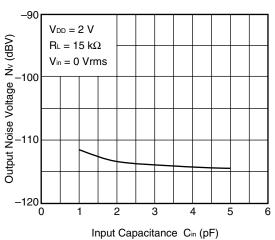


VOLTAGE GAIN vs. INPUT CAPACITANCE



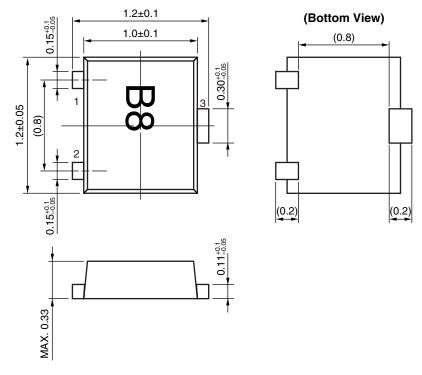
Remark The graphs indicate nominal characteristics.

OUTPUT NOISE VOLTAGE vs. INPUT CAPACITANCE



PACKAGE DIMENSIONS

3-PIN THIN-TYPE LEAD-LESS MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. OUT
- 2. IN
- 3. GND

Remark (): Reference value



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions		Condition Symbol
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Wave Soldering	Peak temperature (molten solder temperature)	: 260°C or below	WS260
	Time at peak temperature	: 10 seconds or less	
	Preheating temperature (package surface temperature)	: 120°C or below	
	Maximum number of flow processes	: 1 time	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (terminal temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

CAUTION

Do not use different soldering methods together (except for partial heating).

Revision History

NE5820M53 Data Sheet

		Description		
Rev.	Date	Page	Summary	
1.00	Jul 9, 2010	-	First edition issued	
2.00	May 20, 2011	p. 2	ABSOLUTE MAXIMUM RATINGS : Operating Ambient Temperature -40 to $+85 \rightarrow -40$ to $+95$	
		p. 2	RECOMMENDED OPERATING RANGE : Supply Voltage MIN. $1.5 \rightarrow 1.0$, MAX. $5.0 \rightarrow 10.0$	
		p. 3	TYPICAL CHARACTERISTICS: Modification of CONSUMPTION CURRENT vs. SUPPLY VOLTAGE, VOLTAGE GAIN vs. SUPPLY VOLTAGE, OUTPUT NOISE VOLTAGE vs. SUPPLY VOLTAGE	

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